

SANYO Semiconductors

DATA SHEET



N-Channel Silicon MOSFET EC4409C — General-Purpose Switching Device **Applications**

Features

- 1.5V drive.
- Halogen Free compliance (UL94 HB).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		0.35	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	1.4	A
Allowable Power Dissipation	PD	When mounted on glass epoxy substrate (145mm×80mm×1.6mm)	0.15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.114
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =100μA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =200mA	360	600		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=200mA, VGS=4V		0.75	1.0	Ω
	R _{DS} (on)2	ID=100mA, VGS=2.5V		0.9	1.3	Ω
	R _{DS} (on)3	ID=10mA, VGS=1.5V		1.8	3.6	Ω
Input Capacitance	Ciss	VDS=10V, f=1MHz		28		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		6.0		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		3.1		pF

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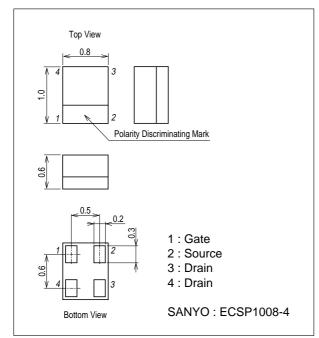
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Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		17.5		ns
Rise Time	tr	See specified Test Circuit.		34.2		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		104		ns
Fall Time	tf	See specified Test Circuit.		55.5		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =350mA		0.87		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =350mA		0.39		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =350mA		0.14		nC
Diode Forward Voltage	V _{SD}	I _S =350mA, V _{GS} =0V		0.86	1.2	V

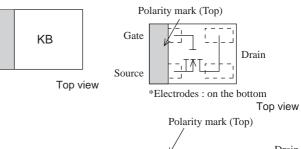
Package Dimensions

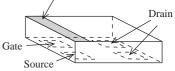
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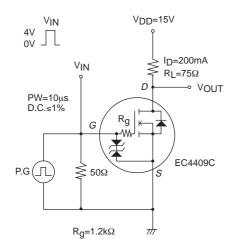
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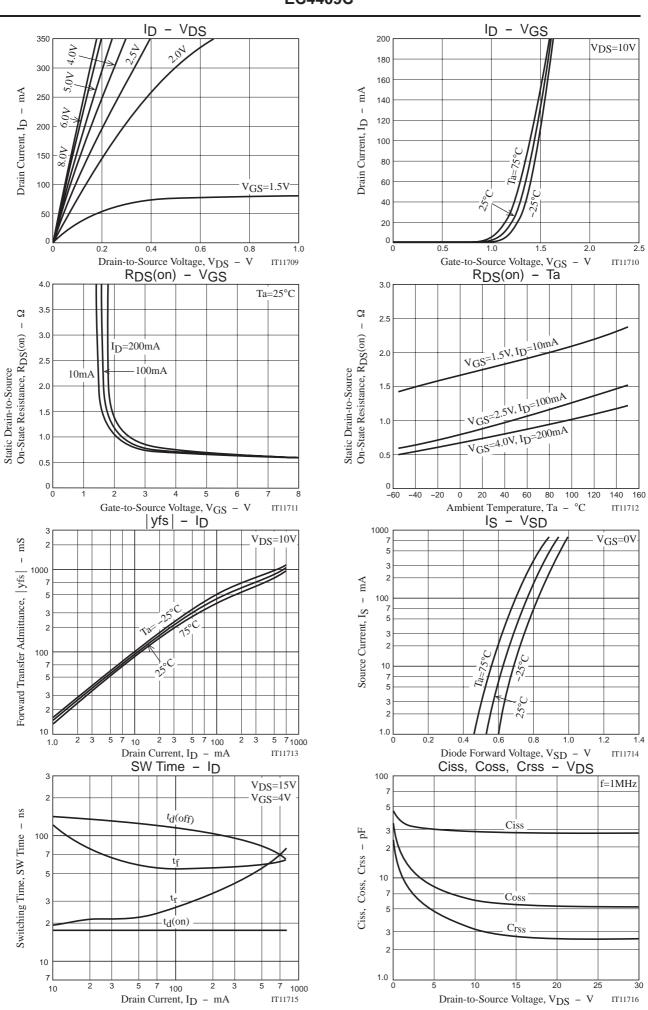
n Electrical Connection

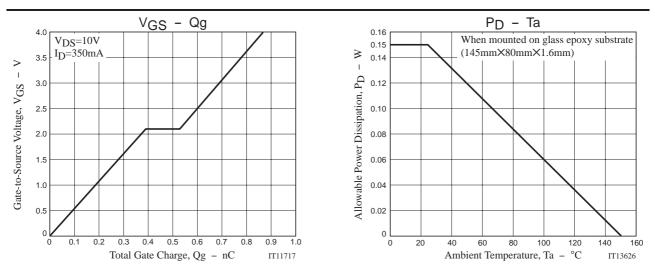




Switching Time Test Circuit







Note on usage : Since the EC4409C is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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